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Rotational Superstructure in van der Waals Heterostructure of Self-Assembled C₆₀ Monolayer on the WSe₂ Surface

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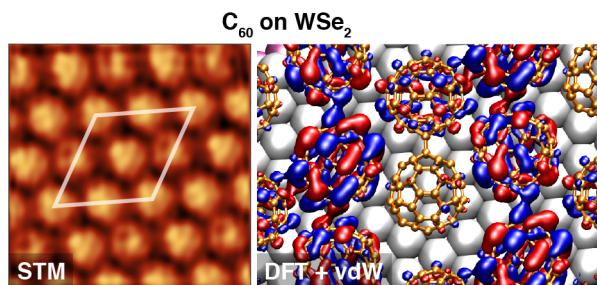
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Abstract

Hybrid van der Waals (vdW) heterostructures composed of two-dimensional (2D) layered materials and self-assembled organic molecules are promising systems for electronic and optoelectronic applications with enhanced properties and performance. Control of molecular assembly is therefore paramount to fundamentally understand the nucleation, ordering, alignment, and electronic interaction of organic molecules with 2D materials. Here, we report the formation and detailed study of highly ordered, crystalline monolayers of C_{60} molecules self-assembled on the surface of WSe_2 in well-ordered arrays with large grain sizes ($\sim 5 \mu m$). Using high-resolution scanning tunneling microscopy (STM), we observe a periodic 2×2 superstructure in the C_{60} monolayer and identify four distinct molecular appearances. Using vdW-corrected *ab initio* density functional theory (DFT) simulations, we determine that the interplay between vdW and Coulomb interactions as well as adsorbate–adsorbate and adsorbate–substrate interactions results in specific rotational arrangements of the molecules forming the superstructure. The orbital ordering through the relative positions of bonds in adjacent molecules create a charge redistribution that links the molecule units in a long-range network. This rotational superstructure extends throughout the self-assembled monolayer and opens a pathway towards engineering aligned hybrid organic/inorganic vdW heterostructures with 2D layered materials in a precise and controlled way.



Graphical abstract

Keywords self-assembly, C_{60} , two-dimensional materials, scanning tunneling microscopy, density functional theory

23 Introduction

24 The intense development of two-dimensional (2D) materials in recent years has expanded into
25 the study of heterostructures formed using 2D layers and other materials.¹⁻⁴ Heterostruc-
26 tures of different materials held together by van der Waals (vdW) forces allow materials
27 of diverse compositions, structures, and properties to be combined, resulting in engineered
28 materials with properties that are combinations of the components' properties, as well as
29 newly emergent behaviours at the interfaces. Such heterostructures have been demonstrated
30 using stacks of 2D layered materials¹⁻⁴ and 2D materials combined with nanostructures of
31 other dimensionalities and with organic crystals.⁵ The atomic flatness and lack of dangling
32 bonds at the surface of 2D layered materials like graphene, boron nitride, and the transition
33 metal dichalcogenides (TMDCs) allow them to form non-covalent interactions with a wide
34 range of materials without the requirements for lattice matching that covalently bonded
35 systems would have. Heterostructures of 2D layers can be achieved by physically stacking
36 different sheets together or by epitaxial growth of subsequent 2D materials.^{1-4,6,7} At the
37 interfaces between disparate materials, effects like charge transfer, tunneling, disorder, and
38 impurity states can influence the electronic and optical behaviours.⁸ The careful combina-
39 tion of materials has resulted in new developments in performance and properties in devices
40 like transistors, solar cells, and light emitting diodes.^{5,9,10}

41 The vdW heterostructures formed by organic crystals on 2D layered materials generally
42 take advantage of the atomically flat and chemically inert surfaces to template self-assembly
43 of the molecule units into ordered arrangements.^{5,11-17} Organic molecules that are often
44 used in organic electronics, which typically have conjugated π -electron systems for better
45 intermolecular conduction,¹⁸ have improved stacking and ordering when they are assembled
46 by 2D materials.¹⁶ This has resulted in devices with significant increases in carrier mobil-
47 ity in field-effect transistors^{5,19,20} and increased charge separation in photovoltaics.²¹ There
48 are also promising opportunities for organic/2D vdW heterostructures to be used in flexible

49 electronics.²²⁻²⁴ The synergy between the mechanical robustness of the 2D layers and their
50 diverse available electronic properties, ranging from semi-metals (e.g. graphene, silicene, ger-
51 manene) to semiconductors (e.g. transition metal dichalcogenides (TMDCs)),²⁵ combined
52 with the chemical tunability of the molecules can open the door for further design rules based
53 on organic/vdW heterostructures. There is a need to develop a fundamental understanding
54 of how molecular processes happening at the early stage of the crystallization of organic
55 molecules on 2D crystals drive the system to specific epitaxial relationships¹¹ and unique
56 interfacial properties such as polymorphism.¹² Moreover, the control of two-dimensional
57 self-assembly of single-layer of molecules on layered materials in terms of molecular order-
58 ing, alignment, and crystallinity can result in emergent behavior and exciting new physics.
59 Therefore, it is essential to achieve a deep understanding of the basic physical and chemical
60 phenomena that rule highly crystalline architectures involving crystals of organic molecules
61 and 2D materials in potential device platforms.

62 Here we report the growth of high quality self-assembled monolayers of C₆₀ on WSe₂ as
63 an example of a weakly interacting organic/2D vdW heterostructure system. C₆₀ has been
64 extensively used in the organic electronics field, and WSe₂ is an important semiconducting 2D
65 material. We study the interfacial properties of this system using complementary methods
66 of high resolution scanning tunneling microscopy (STM) and *ab initio* density functional
67 theory including vdW interactions. C₆₀ plays an important role as an acceptor in organic
68 photovoltaics (OPVs)^{26,27} due to its high electron affinity for charge harvesting processes,
69 and is expected to be similarly useful in hybrid 2D/organic optoelectronics.²⁸ The interfacial
70 interaction of C₆₀ with other 2D TMDCs has been shown to result in doping, with p-
71 doping occurring for WSe₂ in particular,²⁹ and with graphene has led to charge transfer
72 and increased carrier mobility.³⁰ While the self-assembly of C₆₀ molecules on metal surfaces
73 like Cu,³¹⁻³⁴ Au,^{32,35-42} and Ag^{32,35,40} has been widely studied by STM, their behavior on
74 2D material substrates is relatively unknown aside from some studies on graphene.^{15,43-46}
75 The electronic and physical structure of the substrate has played an important role in these

76 earlier works, and is also expected to be crucial in the case of WSe₂. Generally, there is a
77 higher degree of charge transfer between metals and molecules than between 2D materials
78 and molecules.

79 Our STM images reveal that C₆₀ self-assembles into a close-packed monolayer on the
80 surface of WSe₂ that extends uniformly in islands as large as $\sim 5 \mu\text{m}$. The long-range ordering
81 and large grains we observe contrast with much smaller grains and local ordering seen in
82 previous studies. This C₆₀ monolayer exhibits four distinct intramolecular patterns in a 2×2
83 superlattice, which is unusual for a monolayer assembly. High-throughput first-principles
84 calculations show that only a few molecular configurations are energetically favorable for C₆₀
85 arranged on WSe₂. The relative orientation of pentagons and hexagons between neighboring
86 molecules drives the different arrangements through charge reordering connecting the C₆₀
87 molecules in a periodic network. Moreover, a systematic increase of the charge transfer
88 between WSe₂ and C₆₀ is observed as a function of short rotations of C₆₀ mediated by vdW
89 interactions. The increase in electron transfer goes along with the increase in stability of
90 molecular configuration. This observation points to the active role of the molecule–substrate
91 interactions in the stabilization of the interface. This also indicates that the presence of C₆₀
92 has only a mild effect on the physical and electronic properties of WSe₂ (e.g. electronic band
93 gap, W-Se bond length, flatness), even though the molecules are electronically correlated.
94 The creation of a clean interface between WSe₂ and C₆₀ resulting in a unique rotational
95 superlattice is an intriguing step in the understanding and engineering of organic/2D vdW
96 heterojunction devices.

97 **Results and discussion**

98 **Formation of self-assembled C₆₀ monolayer**

99 The assembly of C₆₀ on WSe₂ was experimentally implemented by *in situ* thermal deposi-
100 tion of C₆₀ in an ultrahigh vacuum (UHV) system and characterized by scanning tunneling

101 microscopy (STM). A single-crystal WSe₂ substrate was cleaved by scotch tape to expose a
102 clean surface immediately before being introduced into the vacuum chamber for characteri-
103 zation and thermal deposition of C₆₀. STM images of the clean WSe₂ surface are shown in
104 Fig. 1**a-b**. The atomic structure of the WSe₂ lattice is clearly visible in both images, with
105 a triangular symmetry due to the alternating positions of the Se atoms at the surface. Two
106 point defects are seen in Fig. 1**a**, and some undulation of the surface in Fig. 1**b**. Fullerene
107 molecules (C₆₀) were thermally evaporated in situ onto the WSe₂ surface held at room tem-
108 perature. The deposition time was calibrated such that we achieved sub-monolayer coverage
109 of C₆₀ molecules. A schematic illustration of the C₆₀ molecules on top of WSe₂ is shown in
110 Fig. 1**c**.

111 The sample was then cooled to 55 K for STM imaging, which showed that the fullerenes
112 self-assemble into a close-packed hexagonal layer on WSe₂, as seen in Fig. 1**d**. Because the
113 sample is well below room temperature, the thermal motion of the molecules is minimized so
114 that they can form a stable island with clear boundaries and long-range ordering. We note
115 that bulk C₆₀ crystals, which pack in a face-centered cubic (fcc) lattice, have fewer rotational
116 freedoms below 260 K, and have their orientational alignments frozen below 90 K.^{47,48} In
117 our experiments, the substrate is at room temperature during thermal deposition of C₆₀,
118 allowing sufficient energy for the molecules to rotate and interact. The entire C₆₀/WSe₂
119 system is then gradually cooled to 55 K, so that the optimal molecular configurations are
120 stabilized before STM imaging.

121 The apparent height of the molecules is about 1 nm, as shown in the line profile labeled
122 ‘1’. This height is similar to that of a C₆₀ monolayer grown on NaCl crystals on Au(111), and
123 is higher than the ~0.6-0.7 nm observed for C₆₀ on Au(111).³⁸ The inset of Fig. 1**d** shows a
124 2D fast Fourier transform (FFT) of the C₆₀ region, with sharp points in a hexagonal pattern.
125 The distance from the center to each point is approximately 1.0 nm⁻¹, corresponding to a
126 periodicity of approximately 1.0 nm between molecules. This close-packed arrangement of
127 the C₆₀ on WSe₂ is similar to its arrangement on other substrates such as graphene,^{15,49}

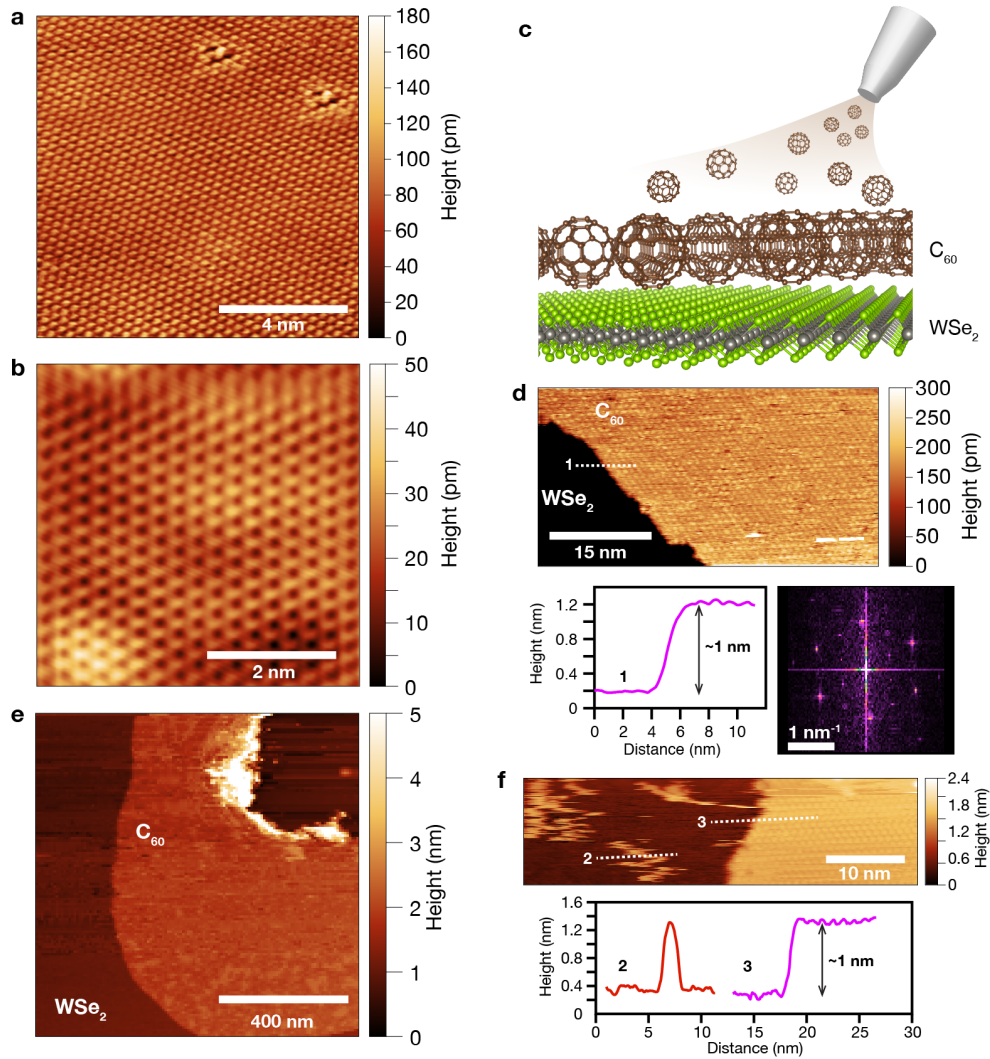


Figure 1: Self-assembly of C_{60} on WSe_2 . (a)-(b) Scanning tunneling microscopy (STM) images of mechanically exfoliated WSe_2 . The atomic lattice is visible in both images, along with two point defects in (a) and some local height variations in (b). Imaging conditions for (a) and (b): 0.6 V sample bias, 1 nA tunneling current setpoint, 55 K sample temperature. (c) Schematic illustration of monolayer of C_{60} deposited by thermal evaporation and self-assembled on WSe_2 surface. (d) STM image of C_{60} self-assembled monolayer island on WSe_2 . The flat WSe_2 surface at the lower left of image appears very dark because the height scale has been adjusted to show periodicity in the C_{60} molecules. Below: Line profile along dashed line 1, showing height of C_{60} molecules is 1 nm, and 2D FFT of the C_{60} molecular arrangement, showing the points corresponding to a hexagonal pattern. Imaging conditions for (d): 2.5 V sample bias, 0.1 nA tunneling current setpoint, 55 K sample temperature. (e) STM image showing larger area of C_{60} island on WSe_2 . Imaging conditions: 3.0 V sample bias, 0.1 nA tunneling current. (f) STM image of the edge of a submonolayer island of C_{60} , showing some molecules moving away from the edge at the left. The heights of the loose molecules and the rest of the island are the same, suggesting that the observed orderly arrangements are monolayers rather than bilayers. Imaging conditions: 2.2 V sample bias, 0.05 nA tunneling current.

128 Au,^{41,42} and Cu.⁴⁶ It is also similar to the (111) cut through the bulk fcc C₆₀ crystal. In
129 contrast, on reactive surfaces with dangling bonds such as Si and SiC, C₆₀ forms covalent
130 bonds with the surface and do not form well-ordered layers,^{50–52} although multilayers of C₆₀
131 can form ordered lattices.⁵³

132 We observe large islands of C₆₀ (Fig. 1e) with dimensions up to $\sim 5 \mu\text{m}$. In contrast,
133 molecular islands of C₆₀ on other substrates in the literature tend to be less than 100 nm
134 in diameter.^{15,38,46} We observe some instances of molecules freely moving across the WSe₂
135 surface with the same apparent 1 nm height, such as the ones in the line profile labeled ‘2’
136 in Fig. 1f, confirming that our molecular islands are indeed monolayers of C₆₀ rather than
137 bilayers. Line profile ‘3’ is taken at the edge of a molecular island.

138 In the high-resolution STM images of Fig. 2, the individual C₆₀ molecules appear to
139 have submolecular structure, relating to the complex shape of the electronic orbitals in the
140 molecule. The distance between adjacent C₆₀ molecules is approximately 1.0 nm (see line
141 profile in Supporting Information, Figure S3). We can identify four individual configurations
142 of C₆₀, as highlighted by the circles labeled i, ii, iii, and iv in Fig. 2a. Each of these molecules
143 is enlarged and cropped in Fig. 2b to more clearly show their distinct appearances. Since
144 sample bias is +2.0 V in these images, these orbitals are likely to correspond to empty states
145 (lowest unoccupied molecular orbitals, LUMO).

146 To understand the variations of the appearance of each C₆₀ molecule on WSe₂, we have
147 performed first-principles density functional theory (DFT) calculations taking into consid-
148 eration van der Waals (vdW) dispersion forces (see Methods section and Supplementary
149 Information for details). As described below in detail, we can identify the most likely inter-
150 face geometry as indicated in each simulated STM image in Fig. 2b. We have simulated the
151 STM images for more than ten different configurations of C₆₀ on top of WSe₂ (see Fig. S1 in
152 Supplementary Materials), with their energies shown in Fig. 3 as discussed in more detail be-
153 low. These configurations can be organized in three different sets of symmetries as described
154 in terms of observed rotational symmetry of the orbital lobes, e.g. 2-, 3- and 5-fold. Each

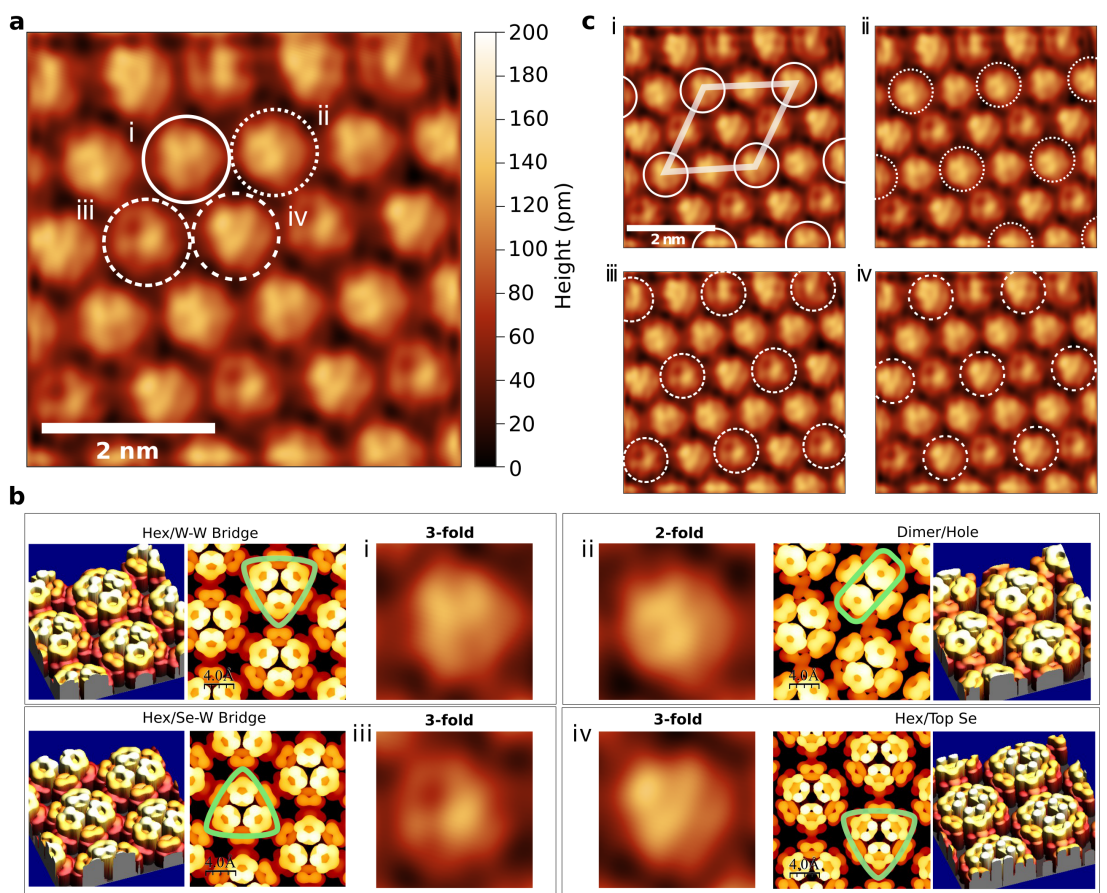


Figure 2: Molecular orientation superlattice of C₆₀ on WSe₂. (a) STM image of self-assembled monolayer of C₆₀ molecules with submolecular resolution showing shapes of orbitals. Since the sample bias is +2.0 V, these are likely empty states (LUMO). The molecules are in a close-packed hexagonal arrangement. Four different orbital appearances are highlighted in the different circles, labeled i, ii, iii, iv, and are potentially attributed to different molecular orientations on the substrate surface. (b) Enlarged and cropped images of the four circled molecules from panel (a), showing their distinct appearances. Simulated STM images in 2D and 3D views are shown beside each panel with the corresponding interface geometries. The dominant symmetry (2-, 3-fold) at each image is highlighted with green-outlines on the simulations. (c) The STM image from panel (a) is repeated here, with each of the four orbital appearances highlighted. They form a 2×2 superlattice arrangement as marked in panel i. Imaging conditions: 2.0 V sample bias, 0.2 nA tunneling current setpoint, 55 K sample temperature.

155 interfacial molecule seems to follow these symmetry rules even at the limit of full surface cov-
156 erage. Indeed, looking closely at this limit we notice that these orbital appearances also form
157 a 2×2 superlattice, as highlighted in Fig. 2c. Each of the appearances i-iv is highlighted in
158 each panel, with the circles indicating the repeated molecules. It is clear that each molecular
159 appearance arises in the self-assembled monolayer of C_{60} every two molecules (Fig. 2c, panel
160 i) to form a hexagonal pattern. In this 2×2 superlattice the distance between nearest neigh-
161 boring molecules is 9.89 \AA , which is close to the vdW distance in C_{60} bulk crystals.⁵⁴ We
162 emphasize here that this 2×2 superlattice is observed in a monolayer of C_{60} , while previous
163 reports of orientational superlattices in C_{60} have been in bilayers on Au(111),⁴² multilayers
164 on Cu(111),⁵⁵ bulk C_{60} crystals,⁵³ multilayers on Ag(111) with some local ordering,⁵⁶ and
165 bilayers and multilayers on NaCl/Au(111).³⁸ There have also been superstructures observed
166 by STM for C_{60} on epitaxial graphene due to electronic Moiré patterns with either the
167 Ru(0001) or SiC(0001) substrates rather than due to molecular rotations.^{15,43}

168 **Configurations and rotations of C_{60} on WSe_2**

169 To determine the effect of the interactions on the observed molecular patterns, we used *ab*
170 *initio* calculations at two different levels of theory with van der Waals interactions (DRSLL
171 functional) and without (GGA, PBE functional). (See Methods section below and Supple-
172 mentary Information for details.) We have initially considered a number of C_{60} molecular
173 configurations on the WSe_2 surface and calculated their electronic and energetic structures
174 for a freestanding layer. A computational high-throughput screening taking into account the
175 orientation of C atoms in the C_{60} molecule in pentagon, hexagon, dimer and apex positions,
176 relative to the WSe_2 structure, resulted in sixteen different arrangements as shown in Fig. 3.
177 We clearly observed the role of vdW dispersion forces in the stabilization of the C_{60}/WSe_2
178 interfaces as we compare Fig. 3a and 3b. There is an enhancement of the stability in the
179 vdW simulations as high as one order of magnitude relative to GGA results. The energy dif-
180 ference between the lowest and the highest stable configurations reaches 0.10 eV and 0.30 eV

181 in GGA and vdW, respectively. We also observed that this increase in stability among the
182 different configurations originates as C_{60} molecules partially rotate on the WSe_2 surface,
183 with the most stable configuration being the one where a hexagonal ring is on top of a Se
184 atom (Hexagon/Top Se, top right of Fig. 3). This effect also influences the amount of charge
185 transferred from WSe_2 towards C_{60} , which follows the vdW stability. As the interactions
186 increase with more stability, the molecular orbitals of the C_{60} overlap more with the states
187 at the surface, which increases the amount of charge transfer towards C_{60} . That is, the
188 more stable the configuration the more electron transfer. This is in accordance with the
189 good acceptor characteristics of C_{60} due to its high electron affinity, which is advantageous
190 in organic solar cells.^{57,58} This also agrees with the spectroscopic observation of C_{60} causing
191 p-doping in WSe_2 .²⁹

192 We now address the different relative orientations between the molecules in the 2×2 su-
193 perlattice measured above (Fig. 2). It is well established that C_{60} molecules tend to perform
194 rotations along some preferential directions when physisorbed on top of weakly interacting
195 surfaces.^{59–65} The strength of molecule–surface interactions and molecule–molecule forces
196 determine the angular orientations of C_{60} , which can vary as a function of temperature.
197 When C_{60} is deposited on WSe_2 surfaces, the molecules will have enough energy to perform
198 molecular spinning, translations and some vibrations, e.g. breathing modes, as simulated
199 using *ab initio* molecular dynamics at 55 K and 355 K (see Fig. 4, and movies in Supplemen-
200 tary Information). Most of the molecules perform short rotations in the first 1.0 ps, assuming
201 different configurations relative to each other at later times. A constant spinning rate of all
202 molecules has not been observed simultaneously for any initial configuration. Fig. 4a shows
203 the initial and final configurations after the system has time evolved for 10.5 ps. The relative
204 positions of the atoms of the C_{60} molecules are highlighted in blue and yellow to follow the
205 evolution with time of the hexagonal and pentagonal rings, respectively, in each molecule.
206 Interestingly, the molecular dynamics indicates that some molecules have their movement
207 coupled to the nearest neighbors through interactions of double bonds localized between two

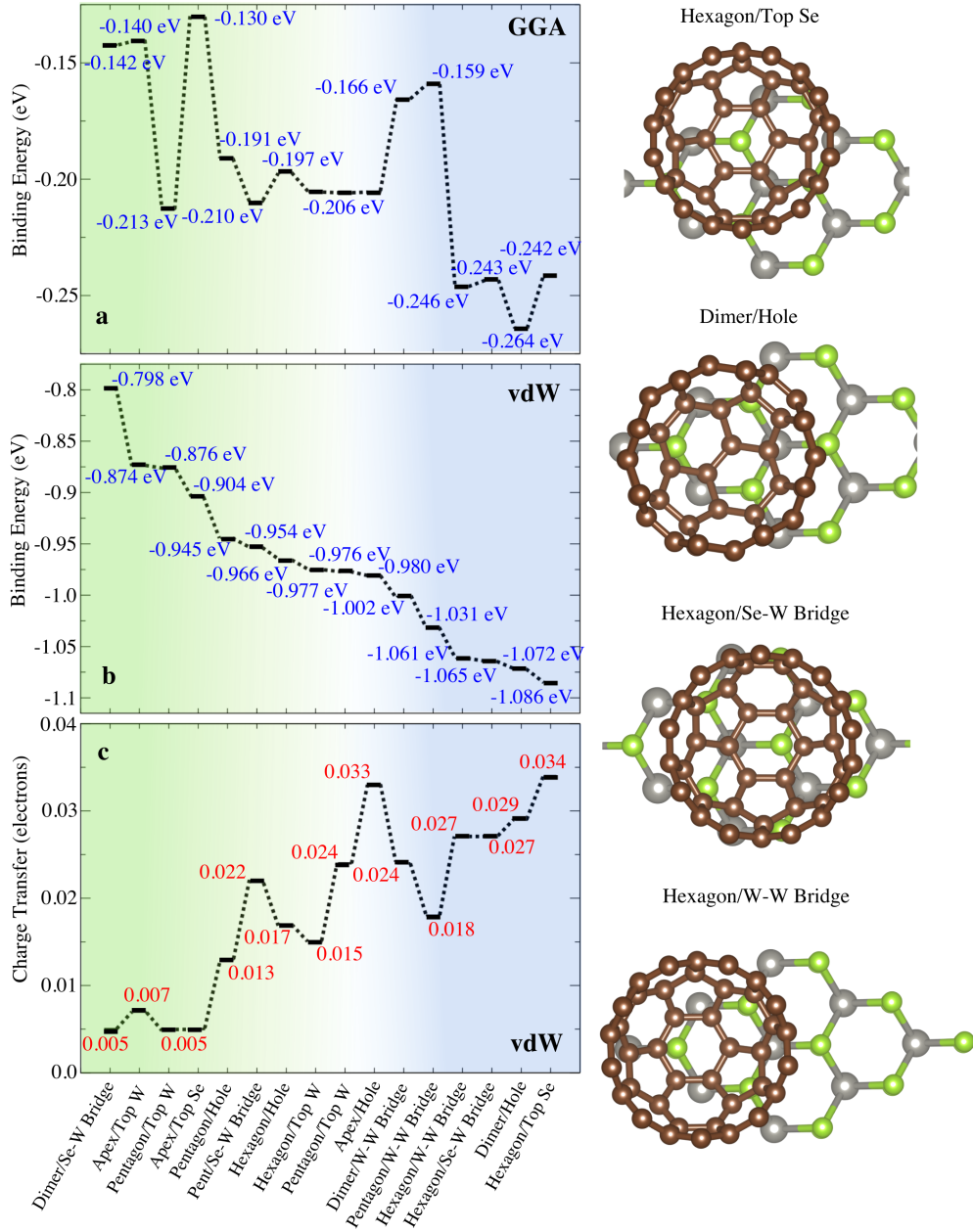


Figure 3: *ab initio* vdW electronic structure calculations. (a),(b) Calculated binding energies per C_{60} molecule at the level of GGA (PBE) and vdW (DRSLL) density functional theory, respectively, for a high-throughput computation screening of several configurations between C_{60} and WSe_2 . Configurations are ordered from the lowest to the highest bindings based on the vdW energy results. The four most stable molecular interfaces are shown on the right side in a top view perspective named accordingly to relative configuration of the C (brown), Mo (gray) and Se (green) atoms. For instance, a hexagonal ring in C_{60} might face the WSe_2 surface in different ways, such as standing on top of a Se atom (Hexagon/Top Se), or at a Se-W bridge position (Hexagon/Se-W bridge). (c) Interfacial charge transfer per molecule calculated at the level of vdW from WSe_2 towards C_{60} .

208 hexagons (6:6) on one molecule and pentagonal faces of an adjacent C_{60} molecule (see movie
209 1 in Supplementary Materials). Such 6:6 bonds have a higher electronic density than bonds
210 localized between a hexagon and pentagon (6:5) because of the local aromatic character.^{54,66}
211 This serves as an efficient point of interactions between the molecules.

212 **Electronic structure of hybrid C_{60} / WSe_2 system**

213 The energetic barriers for rotation between adjacent C_{60} molecules as a function of rotation
214 angle θ (Fig. 4b) show that the most stable positions occur at 0° and 60° , which are angles
215 where a 6:6 bond faces a pentagon (Fig. 4c). In this situation the high charge density of
216 p_z orbitals in 6:6 bonds overlap electron-poor pentagonal zones, which minimizes Coulomb
217 interactions between molecules, therefore reducing the total energy of the system. The ten-
218 dency for electron-rich and electron-poor regions of adjacent C_{60} molecules to associate has
219 been also seen in previous reports.³⁸ The wavefunctions of the conduction band at different
220 rotational angles θ show the different orbital overlaps between the molecules (Fig. 4d-e).
221 In all configurations a substantial interaction is observed, with $\theta = 30^\circ$ corresponding to
222 two 6:6 bonds facing each other as the strongest (Fig. 4e). This configuration raises the
223 energy by ~ 334 meV (Fig. 4b), but provided an efficient coupling between C_{60} molecules as
224 observed in the substantial charge density present throughout the entire system. Repulsive
225 forces based on the short-range Pauli exclusion regime drive the system to short rotations
226 where the strong overlap in wavefunctions between adjacent molecules can be tuned. It is
227 noted that the charge density localized in the inter-molecule space clearly modifies its shape
228 at different values of θ , being more orbital-localized at low interactions energies (Fig. 4d),
229 rather than spread between different molecules at high energy cost (Fig. 4e).

230 Furthermore, some meta-stable positions are also observed around $\theta = 15^\circ$ and $\theta = 45^\circ$,
231 which are due to the stabilization of the charge arrangement between different C_{60} bonds;
232 that is, 6:5 bonds and apex atoms in the C_{60} . This suggests the directional nature of the
233 C_{60} - C_{60} interactions in the monolayer which acts as a driving force for organization and

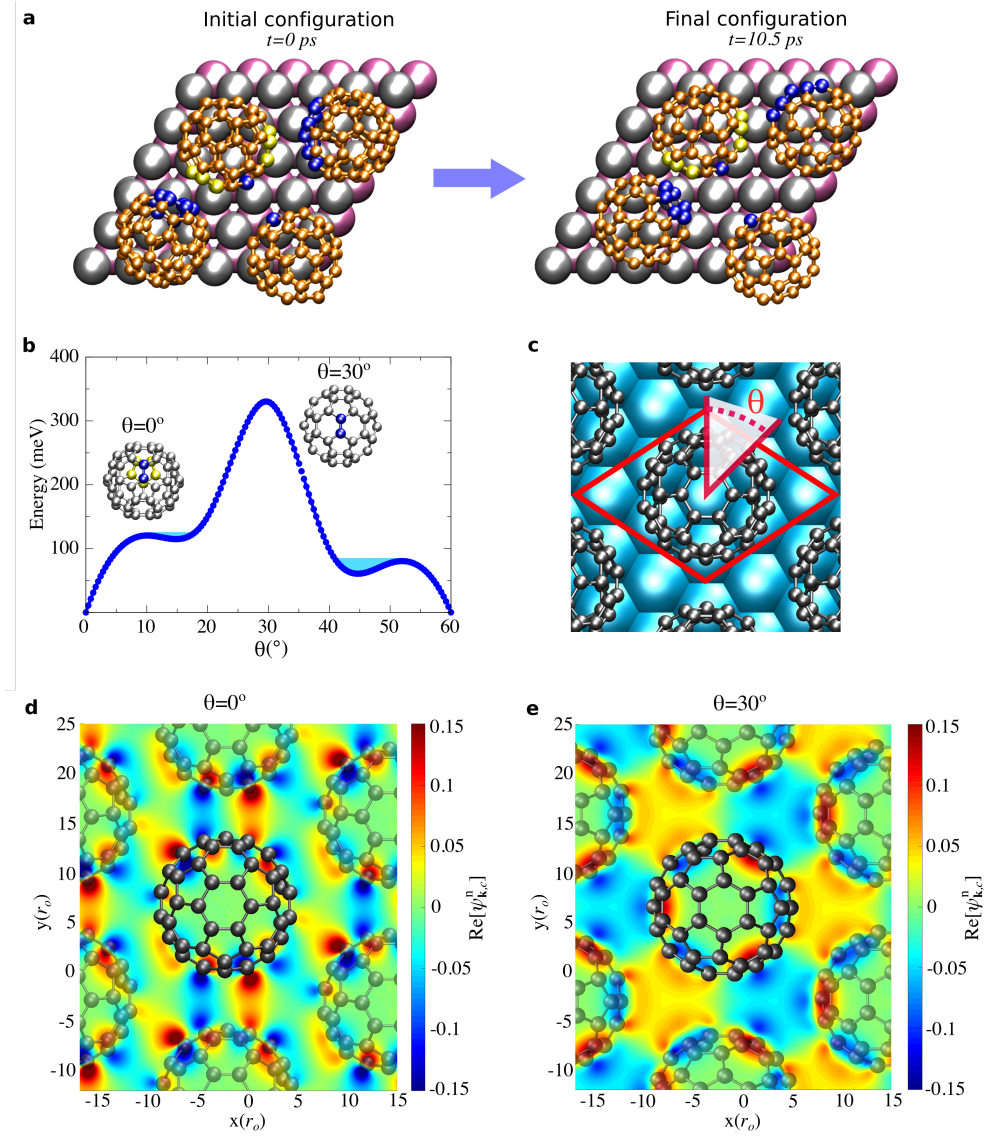


Figure 4: Molecular coupling in C₆₀ molecules. (a) *Ab initio* molecular dynamics simulations including vdW dispersion forces for C₆₀ molecules on WSe₂. Atoms highlighted in blue (involving hexagons) and yellow (involving pentagons) tracked down the evolution of the molecules during the molecular dynamics where most of the interactions between the molecules happen. The system is set at $T = 355$ K, and time-evolved for $t = 10.5$ ps. (b) Rotational barriers per interfacial molecule for C₆₀ at the most stable configuration of Fig.3b (Hexagon/Top Se). (c) Schematic of the unit cell and the definition of the rotational angle θ utilized in b relative to the next-neighbor molecules. The rotational angle θ is defined relative to the equator of the C₆₀ molecule where spinning occurs along its center. Different angles correspond to distinct relative orientations between the C₆₀'s: $\theta = 0^\circ$ (pentagon/6:6 configuration), $\theta = 10^\circ$ (6:5/6:5 configuration), $\theta = 30^\circ$ (6:6/6:6 configuration). Similar orientations are observed for $\theta > 30$ because of the 3-fold symmetry. (d-e) Cross section of the real part of the wave functions corresponding to the bottom of the conduction band $\psi_{\mathbf{k},c}^n$ at $\theta = 0^\circ$ and $\theta = 30^\circ$, respectively. Positive and negative values are shown in the color gradient map at the right of each panel. C atoms are shown in dark gray.

234 self-assembly. Indeed, an estimation of the molecule–molecule interactions in the periodic
235 two-dimensional C_{60} monolayer without the WSe_2 gives a binding energy of 0.70 eV ($\theta = 0$),
236 which is slightly smaller than those calculated between substrate and molecule at different
237 adsorption configurations (Fig.3b) but still in the same energy range. This indicates that
238 some competition between molecule–molecule and molecule–surface interactions takes place
239 at different values of θ . In comparison to experiments performed on other surfaces,^{42,55}
240 where there are stronger interactions between C_{60} molecules and substrates, superlattices
241 were only observed in bilayer islands likely due to the decoupling of the second layer from
242 the substrate. In our experiments, the superlattice is observed in the C_{60} monolayer. If the
243 balance between repulsion and attraction within the C_{60} monolayer is altered due to high
244 molecule–surface interactions, similar patterns would not be observed. We emphasize that
245 here in the case of WSe_2 surfaces, the interactions are at just the right amount to permit
246 the C_{60} molecules to spin and still be chemically coupled to the substrate.

247 The resulting electronic structure of the combined C_{60}/WSe_2 system after 10.5 ps of time
248 evolution is shown in Fig. 5. The geometric configuration of the system is the one shown
249 in Fig. 4a. A band gap of about 0.50 eV is clearly observed in the C_{60}/WSe_2 system, with
250 contributions from conduction band C_{60} states (Fig. 5a). The bandgap of the C_{60} layer
251 alone is close to 0.7 eV, which is considerably smaller than that of C_{60} packed in an FCC
252 solid and smaller than the HOMO-LUMO gap of the isolated molecule,⁵⁴ but is close to
253 what was measured for C_{60} in a double barrier tunnel junction geometry.⁶⁷ This suggests
254 that some delocalization of the C_{60} states throughout the entire system could be a key
255 factor. Indeed, the real part of the fullerene wave functions, $\text{Re}[\psi_{\mathbf{k},c}^n]$ ($n = 4, 7$), selected at
256 the conduction band displayed such behavior (Fig. 5b-c). There is a remarkable electronic
257 interaction between the C_{60} molecules which can be appreciated via the lateral extension of
258 the molecular orbital linking the molecules in different spatial distributions. In fact, such
259 orbital characteristics follow a molecular pattern that resembles the one observed in our
260 STM measurements (Fig. 2). The spatial character of the wave function changes between

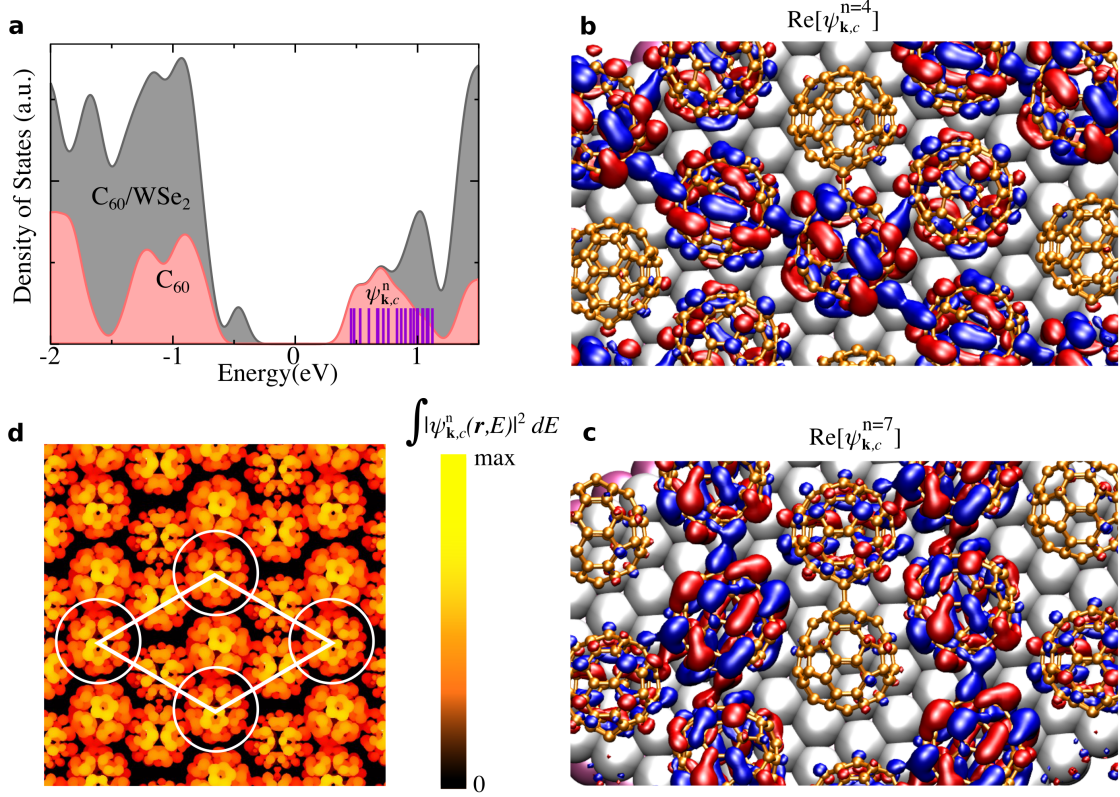


Figure 5: Electronic structure of C_{60}/WSe_2 heterostructure. (a) Density of states (DOS) of the C_{60}/WSe_2 heterostructure (gray) and C_{60} monolayer (pink) for the optimized geometry at 355 K using *ab initio* molecular dynamics simulations as shown in Fig. 4a. The states at the bottom of the conduction band are shown individually through vertical bars with $\psi_{\mathbf{k},c}^n$, where $n = 1 - 19$. Fermi level is set to zero. (b-c) Isosurfaces ($\pm 0.001 e/\text{Bohr}^3$) for the real part of the wave functions corresponding to the fourth and seventh eigenvalues, $\psi_{\mathbf{k},c}^{n=4,7}$ of the DOS represented in panel a. These eigenvalues are arbitrarily chosen to be representative ones from the full set of states at the conduction band. Most of the wave functions show similar interacting patterns between the molecules with slight variations between different $\psi_{\mathbf{k},c}^n$. Here we highlight only two of them, while other examples are shown in Fig. S2. Positive and negative parts of $\psi_{\mathbf{k},c}^n$ are shown in blue and red, respectively. Se, W and C atoms are shown in silver, pink and orange, respectively. (d) Local density of states plotted using the integration of all energy levels marked as $\psi_{\mathbf{k},c}^n$ ($n = 1 - 19$) in a. The periodicity of the 2×2 superlattice is highlighted for a particular C_{60} configuration in the supercell.

261 one eigenvalue to another, not only for $n = 4, 7$, but the orbital symmetry involved at each
 262 molecule is kept the same (see Fig. S2). In particular, all the eigenstates marked in Fig. 5a at
 263 the bottom of the conduction band in the range of 0.45 eV to 1.12 eV inside of the band gap
 264 of the WSe₂ surface have similar electronic characteristics. Integrating these states through:

$$\rho(\mathbf{r}, E) = \int_{E_o}^{E_o+\epsilon} |\psi_{\mathbf{k},c}^n(\mathbf{r}, E)|^2 dE \quad (1)$$

265
 266 gives their spatial distribution in terms of the local density of states as shown in Fig. 5d.
 267 The quantity $\rho(\mathbf{r}, E)$ reproduces closely the main features observed in the measured STM
 268 images (Fig. 2), where every other molecule has the same molecular orbital distribution
 269 following a 2×2 superlattice. The precise combination of the C₆₀ molecules in the supercell
 270 utilized can drive the system to different orientationally ordered C₆₀ domains. However, once
 271 the main interactions between molecules and molecule–substrate take place the rotational
 272 superstructure is formed, even though the local molecular configuration of the individual C₆₀
 273 molecules might show differences. This is related with the dynamical aspect of the molecule
 274 itself associated with the collective character of the self-assembly.

275 Conclusion

276 In conclusion, our findings reveal fundamental knowledge of the physical and chemical phe-
 277 nomena of van der Waals heterostructures using self-assembled organic molecules and in-
 278 organic 2D materials, which have some subtle but important differences from self-assembly
 279 on metal surfaces. C₆₀/WSe₂ constitutes an archetypal vdW heterostructure with excit-
 280 ing possibilities for electronic devices based on atomically thin films. We have shown the
 281 self-assembly of C₆₀ molecules on WSe₂ layers via high-resolution STM and *ab initio* DFT
 282 including vdW interactions. After deposition, the molecules form a monolayer that extends
 283 uniformly over WSe₂ with large grain sizes ($\sim 5 \mu\text{m}$). The interplay and balance between

284 adsorbate–adsorbate and adsorbate–substrate interactions leads to the formation of rota-
285 tional arrays of self-assembled 2×2 molecules. Using the state-of-the-art vdW *ab initio*
286 calculations, we demonstrate the critical role of the relative orientation between specific
287 bonds in the C_{60} in the determination of the spatial superlattice. Through the minimiza-
288 tion of the inter-molecule Coulomb interactions, the C_{60} molecules tend to be electronically
289 coupled with long range orientational ordering, which is reflected in the high crystallinity of
290 C_{60} on WSe_2 . The electronic structure of the hybrid system shows spatial delocalization of
291 molecular orbitals throughout the 2×2 superlattice. The present study shows a mechanism
292 of collective molecular restructuring based on the balance of non-covalent molecule–molecule
293 and molecule–substrate interactions. These results may have implications in the geometrical
294 control of the self-assembly of surface molecules for various electronic and optoelectronic
295 applications based on vdW heterostructures of 2D materials. This highlights the advantages
296 of organic vdW heterostructures over commonly used materials to achieve high-performance
297 organic electronic devices, where such control of molecule assembly is not achievable. Future
298 theoretical and experimental efforts will explore to what extent the surface-driven molec-
299 ular self-assembly mechanism found here will influence the carrier mobility of the organic
300 molecules, which is critical for device platforms.

301 **Methods**

302 **Fabrication of the WSe_2/C_{60} heterostructure and measurements**

303 Ultrahigh vacuum scanning tunneling microscopy (UHV STM) imaging was conducted in an
304 Omicron VT STM/AFM system. The WSe_2 crystal (NanoScience Instruments) was cleaved
305 by peeling away the top layer using adhesive tape in air, and then was immediately loaded
306 into the vacuum system. The C_{60} molecules (Sigma Aldrich, sublimed, 99.9%) were deposited
307 in vacuum using a molecular beam thermal evaporator (Dodecon Nanotechnology GmbH)
308 onto the WSe_2 sample held at room temperature. STM probes were electrochemically etched

309 W wire. The WSe₂ sample with C₆₀ monolayer was cooled to 55 K for all imaging. The
310 STM electronics and software were from Nanonis, and the resulting images were processed
311 with the Gwyddion software package.⁶⁸ Image processing included low-pass noise removal
312 and background flattening.

313 **vdW ab initio calculations**

314 Calculations were based on *ab initio* density functional theory using the SIESTA method⁶⁹
315 and the VASP code.^{70 71} The generalized gradient approximation⁷² along with the DRSSL⁷³
316 functional was used in both methods, together with a double-zeta polarized basis set in
317 SIESTA, and a well-converged plane-wave cutoff of 500 eV in VASP. We used a Fermi-Dirac
318 distribution with an electronic temperature of $k_{BT} = 20$ meV. Additional details are provided
319 in the Supporting Information.

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331 **Author Contributions**

332 Q.H.W. and E.J.G.S. designed the project, analyzed the data, and wrote the manuscript.
333 E.J.G.S. and D.S. conducted the DFT calculations. Q.H.W., N.P.G., X.S.C., and D.O.L.
334 conducted the STM experiments.

335 **Supporting Information**

336 **Supporting Information Available:** Additional details on calculation methods, simulated
337 STM images of all C₆₀ configurations on WSe₂, wavefunctions of C₆₀/WSe₂, and molecular
338 dynamics movies of C₆₀ on WSe₂.

339 **Notes**

340 The authors declare no competing financial interest.

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